TOSHIBA

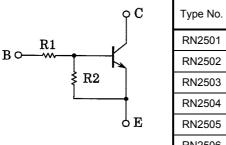
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# RN2501,RN2502,RN2503 RN2504,RN2505,RN2506

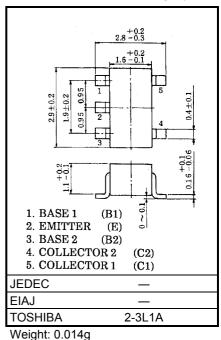
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SMV (super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1501~RN1506

#### **Equivalent Circuit and Bias Resistor Values**



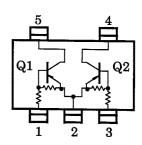
Type No.	R1 (kΩ)	R2 (kΩ)
RN2501	4.7	4.7
RN2502	10	10
RN2503	22	22
RN2504	47	47
RN2505	2.2	47
RN2506	4.7	47



## Equivalent Circuit (Top View)

## Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN2501~2506	V <sub>CBO</sub>	-50	V	
Collector-emitter voltage	RN2301-2300	V <sub>CEO</sub>	-50	V	
Emitter base voltage	RN2501~2504	V <sub>FBO</sub>	-10	v	
	RN2505, 2506	▲EBO	-5		
Collector current		Ι <sub>C</sub>	-100	mA	
Collector power dissipation	RN2501~2506	P <sub>C</sub> *	300	mW	
Junction temperature	RN2501~2500	Tj	150	°C	
Storage temperature range		Tstg	-55~150	°C	



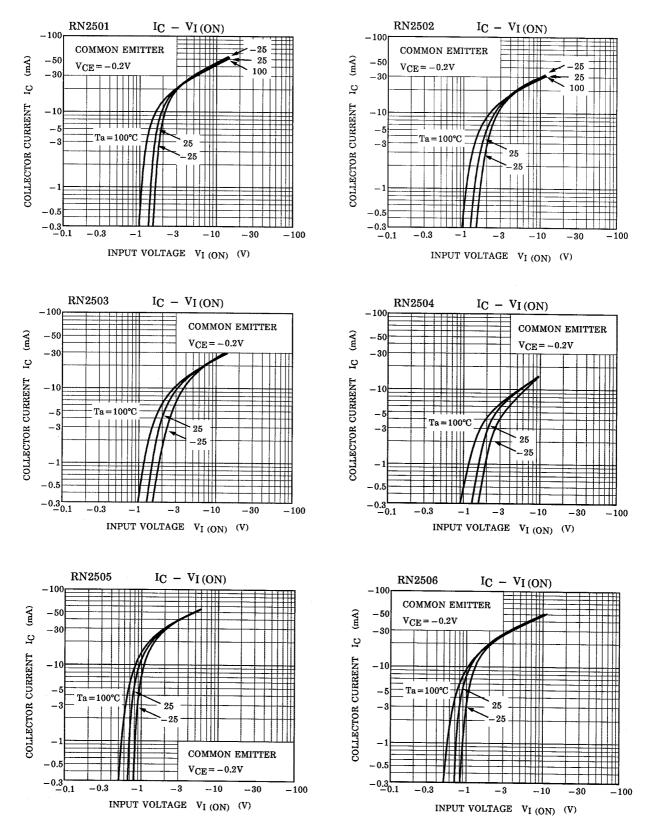
\* Total rating

Unit: mm

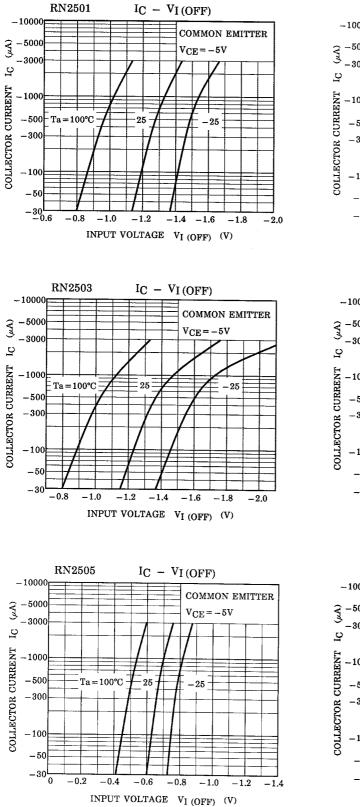
# Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

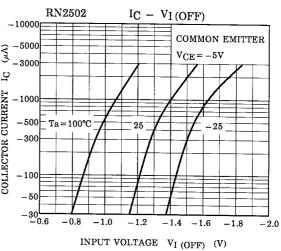
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2501~2506	I <sub>CBO</sub>	_	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
	KN2301*2300	I <sub>CEO</sub>	-	$V_{CE} = -50V, I_B = 0$	_	—	-500	
Emitter cut-off current	RN2501	IEBO	_	V <sub>EB</sub> = -10V, I <sub>C</sub> = 0	-0.82	—	-1.52	- mA
	RN2502		_		-0.38	_	-0.71	
	RN2503		—		-0.17	_	-0.33	
	RN2504		_		-0.082	_	-0.15	
	RN2505		_	- V <sub>EB</sub> = -5V, I <sub>C</sub> = 0	-0.078	_	-0.145	
	RN2506		_		-0.074	_	-0.138	
	RN2501		—		30	_	_	· ·
	RN2502		_		50	_	_	
	RN2503		_	V <sub>CE</sub> = −5V I <sub>C</sub> = −10mA	70	_	_	
DC current gain	RN2504	h <sub>FE</sub>	_		80	_	_	
	RN2505		_		80	_	_	
	RN2506	-	_	-	80	_	_	
Collector-emitter saturation voltage	RN2501~2506	V <sub>CE (sat)</sub>	_	$I_{\rm C} = -5mA$ $I_{\rm B} = -0.25mA$	_	-0.1	-0.3	V
	RN2501	VI (ON)	—	V <sub>CE</sub> = -0.2V I <sub>C</sub> = -5mA	-1.1	_	-2.0	V
	RN2502		_		-1.2	_	-2.4	
	RN2503		_		-1.3	_	-3.0	
Input voltage (ON)	RN2504		_		-1.5	_	-5.0	
	RN2505		_		-0.6	_	-1.1	
	RN2506		_		-0.7	_	-1.3	
	RN2501~2504	VI (OFF)	_	V <sub>CE</sub> = -5V I <sub>C</sub> = -0.1mA	-1.0	_	-1.5	· v
Input voltage (OFF)	RN2505, 2506		_		-0.5	_	-0.8	
Translation frequency	RN2501~2506	f <sub>T</sub>	_	V <sub>CE</sub> = -10V I <sub>C</sub> = -5mA	_	200	_	MHz
Collector output capacitance	RN2501~2506	C <sub>ob</sub>	_	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0 f = 1MHz	_	3	6	pF
	RN2501		—	-	3.29	4.7	6.11	- kΩ
	RN2502	- R1	_		7	10	13	
Input resistor	RN2503		_		15.4	22	28.6	
	RN2504		_		32.9	47	61.1	
	RN2505		_		1.54	2.2	2.2 2.86	
	RN2506		_		3.29	4.7	6.11	
	RN2501~2504		_		0.9	1.0	1.1	
Resistor ratio	RN2505	R1/R2	_		0.0421	0.0468	0.0515	
	RN2506		_		0.09	0.1	0.11	

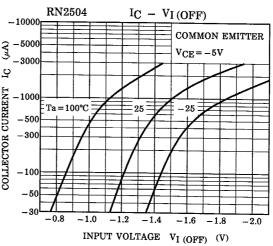
### (Q1, Q2 Common)

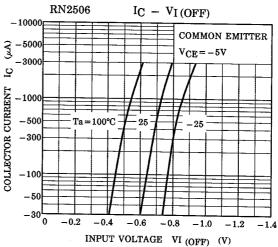


#### (Q1, Q2 Common)

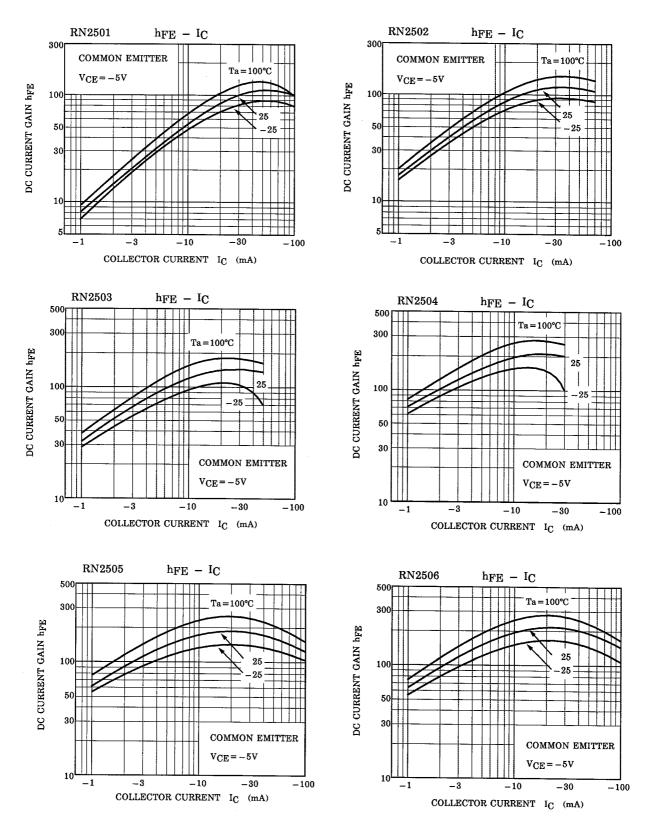








### (Q1, Q2 Common)



Type Name	Marking
RN2501	Y A HEE
RN2502	Type Name Y B UUU
RN2503	Type Name YC UUU
RN2504	Type Name Y D HHH
RN2505	Type Name Y E B B B
RN2506	Type Name Y F UUU

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